

L Number	Hits	Search Text	DB	Time stamp
1	2	5539224.pn.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/10/01 15:31
2	17	5539224.URPN.	USPAT	2004/10/01 15:22
3	2	5342794.pn.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/10/01 15:57
4	2	704115.ap.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/10/01 15:35
5	2	5286518.pn.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/10/01 16:02
6	0	5313079pn.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/10/01 16:02
7	2	5313079.pn.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/10/01 16:02
-	17993	((n adj channel) or "n-channel") same ((p adj channel) or "p-channel") same drain same gate	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/10/01 15:20
-	13832	((n adj channel) or "n-channel") same ((p adj channel) or "p-channel") same (drain with gate)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/04/06 17:17
-	3587	((n adj channel) or "n-channel") same ((p adj channel) or "p-channel") same (drain with gate) same inverter	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/04/06 17:17
-	72	((n adj channel) or "n-channel") same ((p adj channel) or "p-channel") same (drain with gate) same inverter) same polysilicon	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/04/06 17:17
-	659	((n adj channel) or "n-channel") same ((p adj channel) or "p-channel") same (drain with gate with polysilicon)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/04/06 17:17
-	41	((n adj channel) or "n-channel") same ((p adj channel) or "p-channel") same (drain with gate with polysilicon) same inverter	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/04/06 17:17
-	20	((n adj channel) or "n-channel") same ((p adj channel) or "p-channel") same (drain with gate with polysilicon) same inverter) and (@ad<19931227 or @rlad<19931227)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/04/06 17:33
-	17	((n adj channel) or "n-channel") with ((p adj channel) or "p-channel") with drain with gate with "same" with silicon	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/04/06 17:54
-	9	((n adj channel) or "n-channel") with ((p adj channel) or "p-channel") with drain with gate with "same" with silicon) and (@ad<19931227 or @rlad<19931227)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/04/06 17:39
-	0	(trace with gate with coplanar) and (@ad<19931227 or @rlad<19931227)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/09/30 16:18

-	10	trace with gate with coplanar	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/04/06 17:39
-	27	((n adj channel) or "n-channel") with ((p adj channel) or "p-channel") same (drain with gate with "same" with silicon with form\$3)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/04/06 18:02
-	17	((n adj channel) or "n-channel") with ((p adj channel) or "p-channel") same (drain with gate with "same" with silicon with form\$3)) and (@ad<19931227 or @rlad<19931227)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/04/06 17:55
-	4	drain with gate with "same" with silicon with elevated	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/04/06 18:03
-	130	drain with gate with silicon with elevated	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/04/06 18:13
-	24	(drain with gate with silicon with elevated) and (@ad<19931227 or @rlad<19931227)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/04/07 12:17
-	11	((drain with gate with silicon with elevated) and (@ad<19931227 or @rlad<19931227)) and ((n adj channel) or "n-channel") same ((p adj channel) or "p-channel")	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/04/06 18:05
-	113	drain with gate with silicon with raised	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/04/06 18:14
-	17	(drain with gate with silicon with raised) and (@ad<19931227 or @rlad<19931227)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/04/06 18:24
-	1058	((n adj channel) or "n-channel") same ((p adj channel) or "p-channel") and (drain with "same" with gate with layer)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/04/07 13:02
-	326	((n adj channel) or "n-channel") same ((p adj channel) or "p-channel") and (drain with "same" with gate with layer)) and (@ad<19931227 or @rlad<19931227)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/04/07 12:17
-	198	((n adj channel) or "n-channel") same ((p adj channel) or "p-channel") same (drain with "same" with gate with layer)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/04/07 12:17
-	80	((n adj channel) or "n-channel") same ((p adj channel) or "p-channel") same (drain with "same" with gate with layer)) and (@ad<19931227 or @rlad<19931227)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/04/07 12:52
-	16994	etch\$3 with gate with substrate	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/04/07 12:53
-	0	(etch\$3 with gate with substrate) with from	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/04/07 12:51
-	269	(etch\$3 with gate with substrate) same (drain with gate with "same" with layer)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/04/07 12:54
-	57	((etch\$3 with gate with substrate) same (drain with gate with "same" with layer)) and (@ad<19931227 or @rlad<19931227)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/04/07 12:54

-	2888	form\$3 with gate with (substrate near2 etch\$3)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/04/07 12:54
-	25	(form\$3 with gate with (substrate near2 etch\$3)) same (drain with gate with "same" with layer)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/04/07 14:50
-	5	((form\$3 with gate with (substrate near2 etch\$3)) same (drain with gate with "same" with layer)) and (@ad<19931227 or @rlad<19931227)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/04/07 13:02
-	217	inverter with trace	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/04/07 13:01
-	4	((inverter with trace) and ((n adj channel) or "n-channel") same ((p adj channel) or "p-channel")) and (@ad<19931227 or @rlad<19931227)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/04/07 13:32
-	25	(inverter with trace) and ((n adj channel) or "n-channel") same ((p adj channel) or "p-channel")	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/04/07 13:07
-	125	trace with connect\$3 with drain	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/04/07 13:31
-	26	(trace with connect\$3 with drain) and (@ad<19931227 or @rlad<19931227)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/04/07 14:51
-	3	("4181860"   "4387433"   "4433384").PN.	USPAT	2004/04/07 14:44
-	1694	connect\$3 with drain with "adjacent" with transistor	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/04/07 14:49
-	33	(connect\$3 with drain with "adjacent" with transistor) same (drain with gate with "same" with layer)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/04/07 14:51
-	15	((connect\$3 with drain with "adjacent" with transistor) same (drain with gate with "same" with layer)) and (@ad<19931227 or @rlad<19931227)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/04/07 15:08
-	29	cmos with gate with drain with form\$3 with "same" with layer	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/04/07 15:13
-	9	(cmos with gate with drain with form\$3 with "same" with layer) and (@ad<19931227 or @rlad<19931227)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/04/07 15:14
-	18	inverter same (gate with drain with form\$3 with "same" with layer)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/04/07 15:14
-	8	(inverter same (gate with drain with form\$3 with "same" with layer)) and (@ad<19931227 or @rlad<19931227)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/04/07 16:05
-	0	(macro same (first with layer with metallization) same (second with layer with metallization with interconnect with macro)) and (@ad<19931227 or @rlad<19931227)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/04/07 16:06
-	2	(macro same ((first or second) with layer with metallization) same (interconnect with macro)) and (@ad<19931227 or @rlad<19931227)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/04/07 16:08

-	4	(macro and ((first or second) with layer with metallization) and (interconnect with macro)) and (@ad<19931227 or @rlad<19931227)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/04/07 17:36
-	4	(macro with embed\$4 with standard) and (@ad<19931227 or @rlad<19931227)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/04/07 17:43
-	0	(macro with pitch with standard) and (@ad<19931227 or @rlad<19931227)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/04/07 17:43
-	0	((macro with standard) same pitch) and (@ad<19931227 or @rlad<19931227)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/04/07 17:43
-	15	((macro with standard) same pitch)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/04/07 18:02
-	2	5539224.pn.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/04/07 18:05
-	2	5342794.pn.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/04/07 18:07
-	3	3461361.pn.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/04/07 18:08
-	2	5286518.pn.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/04/07 18:12
-	2	5410173.pn.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/04/07 18:13
-	2	4742383.pn.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/04/07 18:14
-	2	5313079.pn.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/04/07 18:15
-	2	5671397.pn.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/04/08 17:04
-	0	us-2002/0153574-\$.did.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/04/08 17:06
-	6	125925.ap.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/04/08 17:06
-	2638	(connect\$3 with drain) same (cmos with inverter)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/09/30 16:19
-	2	6605499.pn.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/09/30 16:14
-	2	6269466.pn.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/09/30 16:14

-	2	5671397.pn.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/09/30 16:16
-	6	174654.ap.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/09/30 16:16
-	1162	((connect\$3 with drain) same (cmos with inverter)) and (@ad<19931227 or @rlad<19931227)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/09/30 16:20
-	1	((connect\$3 with drain) same (cmos with inverter)) same trace	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/09/30 16:18
-	1206	(connect\$3 with drain) with (cmos with inverter)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/09/30 16:19
-	559	((connect\$3 with drain) with (cmos with inverter)) and (@ad<19931227 or @rlad<19931227)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/09/30 16:21
-	388	((connect\$3 with drain) with (cmos with inverter)) and (@ad<19931227 or @rlad<19931227)) and (n adj (channel or well)) and (p adj (channel or well))	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/09/30 16:21
-	455	((connect\$3 with drain) with (cmos with inverter)) same (n adj (channel or well)) same (p adj (channel or well))	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/09/30 16:21
-	248	((connect\$3 with drain) with (cmos with inverter)) same (n adj (channel or well)) same (p adj (channel or well))) and (@ad<19931227 or @rlad<19931227)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/09/30 16:46
-	39	((connect\$3 with drain) with (cmos with inverter)) same (n adj (channel or well)) same (p adj (channel or well))) and (@ad<19931227 or @rlad<19931227)) and 257/\$3.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/09/30 17:33
-	30	(cmos adj inverter) and (gate with interconnect with drain with \$4silicon)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/09/30 17:25
-	19	((cmos adj inverter) and (gate with interconnect with drain with \$4silicon)) and (@ad<19931227 or @rlad<19931227)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/09/30 17:33
-	231	(cmos adj inverter) and (gate with connect\$3 with drain with \$4silicon)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/09/30 17:25
-	111	((cmos adj inverter) and (gate with connect\$3 with drain with \$4silicon)) and 257/\$3.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/09/30 17:33
-	53	((cmos adj inverter) and (gate with connect\$3 with drain with \$4silicon)) and 257/\$3.ccls.) and (@ad<19931227 or @rlad<19931227)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/10/01 11:56
-	920	(form\$3 with gate with (trace or interconnect\$3 or connect\$3) with drain with (polysilicon or silicon)) and (@ad<19931227 or @rlad<19931227)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/10/01 11:58
-	71	((form\$3 with gate with (trace or interconnect\$3 or connect\$3) with drain with (polysilicon or silicon)) and (@ad<19931227 or @rlad<19931227)) and (cmos adj inverter)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/10/01 11:59

-	299	(form\$3 with gate with ((trace or interconnect\$3 or connect\$3) near2 drain) with (polysilicon or silicon)) and (@ad<19931227 or @rlad<19931227)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/10/01 11:58
-	38	((form\$3 with gate with ((trace or interconnect\$3 or connect\$3) near2 drain) with (polysilicon or silicon)) and (@ad<19931227 or @rlad<19931227)) and (cmos adj inverter)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/10/01 11:59